## **Pin Configurations**

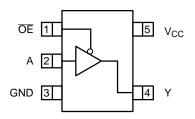


Figure 2. SC-88A and SC-74A (Top View)

# OE 1 6 V<sub>CC</sub> 5 NC A 2 GND 3 4 Y

Figure 3. MicroPak (Top Through View)

## **PIN DEFINITIONS**

Pin # SC-88A / SC74A	Pin # MicroPak	Name	Description
1	1	ŌĒ	Input
2	2	Α	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V <sub>CC</sub>	Supply Voltage
	5	NC	No Connect

## **FUNCTION TABLE**

Inputs		Output
ŌĒ	Α	Y
L	L	L
L	Н	Н
Н	Х	Z

H = HIGH Logic Level L = LOW Logic Level X = HIGH or LOW Logic Level Z = HIGH Impedance State

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5	6.5	V
V <sub>OUT</sub>	DC Output Voltage		-0.5	6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < 0 V	-	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < 0 V	-	-50	mA
I <sub>OUT</sub>	DC Output Current		-	±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current		-	±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias		-	+150	°C
T <sub>L</sub>	Junction Lead Temperature (Sold	ering, 10 Seconds)	-	+260	°C
$P_{D}$	Power Dissipation in Still Air	SC-74A	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™-6	-	812	
ESD	Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC: J	ESD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage Operating		1.65	5.50	V
	Supply Voltage Data Retention		1.50	5.50	
V <sub>IN</sub>	Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage	Active State	0	V <sub>CC</sub>	V
		Three-State	0	5.5	
T <sub>A</sub>	Operating Temperature		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	t <sub>r</sub> , t <sub>f</sub> Input Rise and Fall Times	V <sub>CC</sub> at 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V <sub>CC</sub> at 3.3 V ±0.3 V	0	10	
		V <sub>CC</sub> at 5.0 V ±0.5 V	0	5	
$\theta_{\sf JA}$	Thermal Resistance	SC-74A	_	320	°C/W
		SC-88A	_	377	
		MicroPak-6	_	154	
		MicroPak2-6	_	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

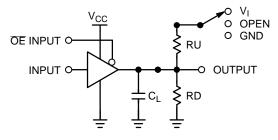
## DC ELECTICAL CHARACTERISTICS

				T,	λ = +25°	°C	$T_A = -40$	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage	1.65 to 1.95		0.65 V <sub>CC</sub>	-	-	0.65 V <sub>CC</sub>	-	V
		2.30 to 5.50		0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
$V_{IL}$	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
		2.30 to 5.50		-	-	0.30 V <sub>CC</sub>	-	0.30 V <sub>CC</sub>	
V <sub>OH</sub>	HIGH Level Output Voltage	1.65	$V_{IN} = V_{IH} \text{ or } V_{IL},$	1.55	1.65	-	1.55	-	V
		1.80	$I_{OH} = -100 \mu\text{A}$	1.70	1.80	-	1.70	-	
		2.30		2.20	2.30	-	2.20	_	
		3.00		2.90	3.00	-	2.90	_	
		4.50		4.40	4.50	-	4.40	_	
		1.65	$I_{OH} = -4 \text{ mA}$	1.29	1.52	-	1.29	_	
		2.30	I <sub>OH</sub> = -8 mA	1.90	2.15	-	1.90	_	1
		3.00	I <sub>OH</sub> = -16 mA	2.40	2.80	-	2.40	_	
		3.00	I <sub>OH</sub> = -24 mA	2.30	2.68	-	2.30	_	
		4.50	$I_{OH} = -32 \text{ mA}$	3.80	4.20	-	3.80	_	
V <sub>OL</sub>	LOW Level Output Voltage	1.65	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OL} = 100 \mu A$	_	0.00	0.10	-	0.00	V
		1.80		_	0.00	0.10	_	0.10	
		2.30		_	0.00	0.10	-	0.10	
		3.00		_	0.00	0.10	-	0.10	
		4.50		_	0.00	0.10	_	0.10	
		1.65	I <sub>OL</sub> = 4 mA	_	0.80	0.24	-	0.24	
		2.30	I <sub>OL</sub> = 8 mA	_	0.10	0.30	-	0.30	
		3.00	I <sub>OL</sub> = 16 mA	-	0.15	0.40	-	0.40	
		3.00	I <sub>OL</sub> = 24 mA	-	0.22	0.55	-	0.55	
		4.50	I <sub>OL</sub> = 32 mA	-	0.22	0.55	-	0.55	
I <sub>IN</sub>	Input Leakage Current	1.65 to 5.5	$0 \ge V_{IN} \ge 5.5 \text{ V}$	-	_	±1	-	±10	μΑ
I <sub>OZ</sub>	3-STATE Output Leakage	0 to 5.5	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $0 \ge V_O \ge 5.5 \text{ V}$	_	_	±1	_	±10	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	0	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	-	_	1	-	10	μΑ
Icc	Quiescent Supply Current	1.65 to 5.50	V <sub>IN</sub> = 5.5 V, GND	-	_	2	-	20	μΑ

## **AC ELECTRICAL CHARACTERISTICS**

				-	Γ <sub>A</sub> = +25°C	;	$T_A = -40$	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay (Figure 4, 6)	1.65	C <sub>L</sub> = 15 pF,	-	6.4	13.2	-	13.8	ns
		1.80	$R_D = 1 M\Omega$ $S_1 = OPEN$	-	5.3	11.0	-	11.5	
		2.50 ±0.20	]	-	3.4	7.5	-	8.0	
		3.30 ±0.30	]	-	2.5	5.2	-	5.5	
		5.00 ±0.50	]	-	2.1	4.5	-	4.8	
		3.30 ±0.30	C <sub>L</sub> = 50 pF,	-	3.2	5.7	-	6.0	
		5.00 ±0.50	$R_D = 500 \Omega$ $S_1 = OPEN$	-	2.6	5.0	-	5.3	
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time (Figure 4, 6)	1.65	$\begin{split} &C_L = 50 \text{ pF,} \\ &R_D = 500 \Omega \\ &RU = 500 \Omega \\ &S_1 = \text{GND for t}_{PZH} \\ &S_1 = V_{IN} \text{ for t}_{PZL} \\ &V_{IN} = 2 \cdot V_{CC} \end{split}$	-	8.4	15.0	_	15.6	ns
		1.80		-	7.0	12.5	-	13.0	
		2.50 ±0.20		-	4.6	8.5	-	9.0	]
		3.30 ±0.30		-	3.5	6.2	-	6.5	
		5.00 ±0.50		-	2.8	5.5	-	5.8	
$t_{PLZ}, t_{PHZ}$	Output Disable Time (Figure 4, 6)	1.65	$C_L = 50 \text{ pF},$ $R_D = 500 \Omega$	1	6.5	13.2	_	14.5	
	(Figure 4, 6)	1.80	$RU = 500 \Omega$	-	5.4	11.0	-	12.0	
		2.50 ±0.20	$S_1 = GND \text{ for } t_{PHZ}$ $S_1 = V_{IN} \text{ for } t_{PLZ}$	1	3.5	8.0	-	8.5	
		3.30 ±0.30	$V_{IN} = 2 \cdot V_{CC}$	-	2.8	5.7	-	6.0	
		5.00 ±0.50		ı	2.1	4.7	_	5.0	
C <sub>IN</sub>	Input Capacitance	0.00		ı	4	_	_	_	pF
C <sub>OUT</sub>	Output Capacitance	0.00		ı	8	_	_	_	
C <sub>PD</sub>	Power Dissipation Capacitance (Note 2) (Figure 5)	3.30		_	17	-	-	-	pF

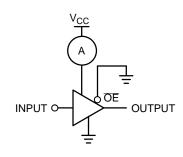
<sup>2.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression:
I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).



#### NOTE:

3.  $C_L$  includes load and stray capacitance; Input PRR = 1.0 MHz;  $t_W$  = 500 ns

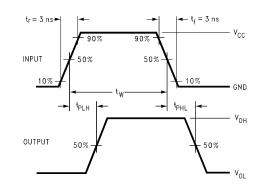
Figure 4. AC Test Circuit



## NOTE:

4. Input = AC Waveform;  $t_r = t_f = 1.8$  ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 5. I<sub>CCD</sub> Test Circuit



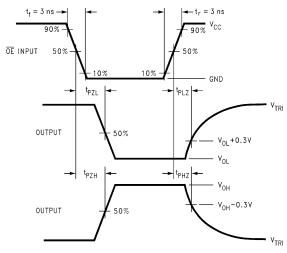


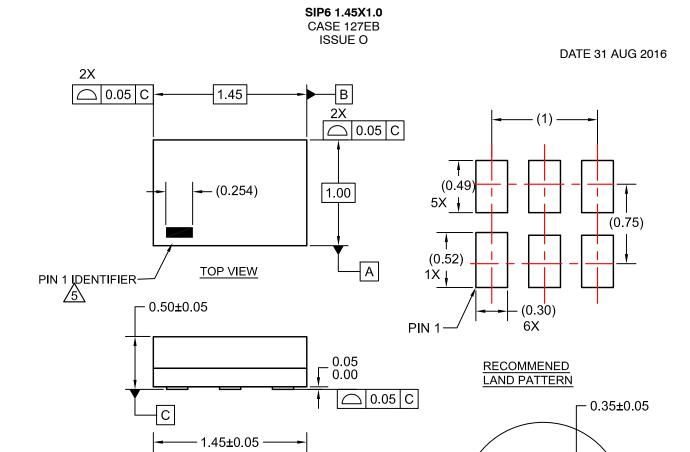
Figure 6. AC Waveforms

#### ORDERING INFORMATION

Part Number	Top Mark	Operating Temperature	Packages	Shipping <sup>†</sup>
NC7SZ125M5X	7Z25	–40 to +85°C	SC-74A	3000 / Tape & Reel
NC7SZ125P5X	Z25	–40 to +85°C	SC-88A	3000 / Tape & Reel
NC7SZ125L6X	DD	–40 to +85°C	MicroPak	5000 / Tape & Reel
NC7SZ125FHX	DD	–40 to +85°C	MicroPak2	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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0.20±0.05 6X

0.10(M)0.05(M)

0.30±0.05 5X

0.35±0.05 5X

(0.125)

4X

C B A

0.075 X 45°

CHAMFER

NOTES:

DETAIL A

1.00±0.05

(0.050)

6X

1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD

0.5

1.0

- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
  4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

**BOTTOM VIEW** 

- - OTHER LINE IN THE MARK CODE LAYOUT.

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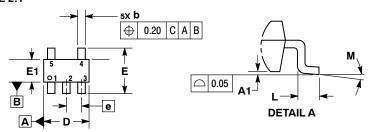
0.40±0.05

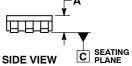
**PIN 1 TERMINAL** 

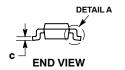
**DETAIL** A



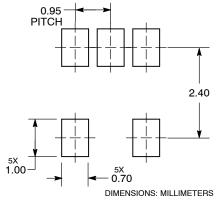
**DATE 18 JAN 2018** 











\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
  Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE
  MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.90	1.10		
A1	0.01	0.10		
b	0.25	0.50		
С	0.10	0.26		
D	2.85	3.15		
E	2.50	3.00		
E1	1.35	1.65		
е	0.95 BSC			
L	0.20	0.60		
М	0 °	10°		

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

**DATE 17 JAN 2013** 



- TIES:
  DIMENSIONING AND TOLERANCING
  PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

## **GENERIC MARKING DIAGRAM\***



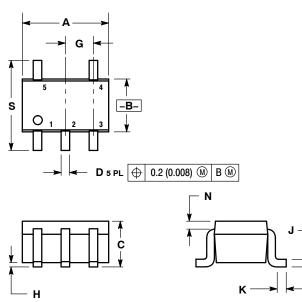
XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



			0.65 0.025
0.40			0.65 0.025
_	<u>1.9</u> 0.0748	SCALE 20:1	$\left(\frac{\text{mm}}{\text{inches}}\right)$

**SOLDER FOOTPRINT** 

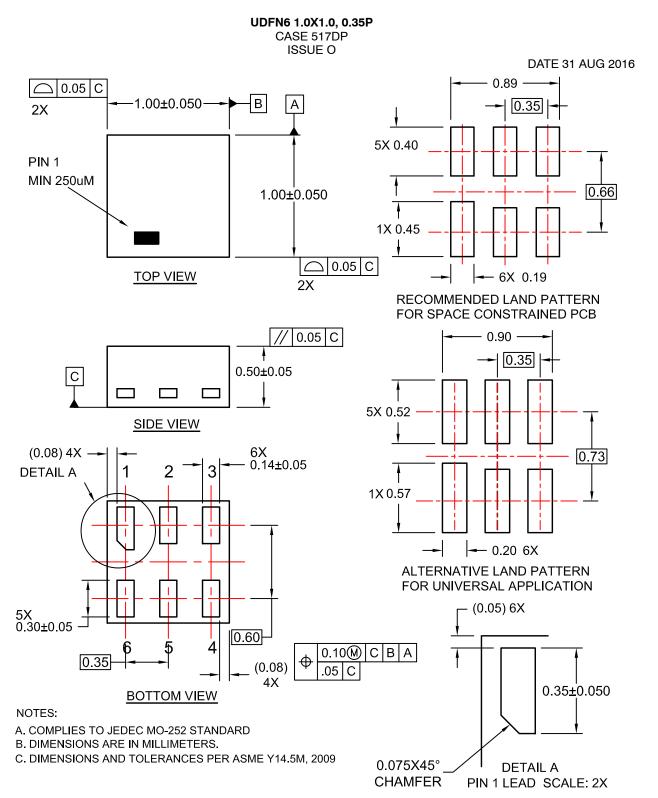
0.50

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4
5. COLLECTOR	5. CATHODE	5. CATHODE 1	5. GATE 2	5. CATHODE 4

5. COLLECTOR	5. CATHODE	5. CATHODE 1	5. GATE 2	5. CATHODE 3
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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